



ULTRA LOW PHASE NOISE AMPLIFIER, 6 - 12 GHz

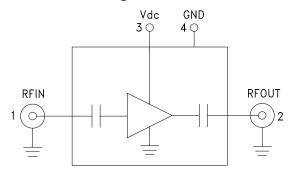


Typical Applications

The HMC-C072 is ideal for:

- Microwave Radio
- Military & Space
- Test Instrumentation
- VSAT

Functional Diagram



Features

Ultra Low Phase Noise: -167 dBc/Hz @ 1 kHz

Noise Figure: 4.5 dB

Gain: 11 dB Psat: 22 dBm

50 Ohm Matched Input/Output

Single Supply Voltage: +7V @ 170mA

Hermetically Sealed Module

Field Replaceable SMA Connectors
-55 °C to +85 °C Operating Temperature

General Description

The HMC-C072 is a GaAs HBT Ultra Low Noise Amplifier in a miniature, hermetic module designed to operate between 6 and 12 GHz. This high dynamic range amplifier module provides 11 dB of gain, 4.5 dB noise figure and up to 23 dB of output power with a single supply of +7V. The ultra low phase noise contribution of -167 dBc/Hz at 1 kHz offset, enables superior modulation accuracy within transceiver architectures. The wideband distributed amplifier I/O's are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_A = +25$ °C, Vdc = +7V

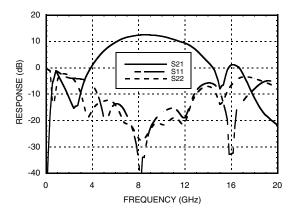
Parameter	Min.	Тур.	Max.	Units
Frequency Range	6 - 12		GHz	
Gain	9	11		dB
Gain Flatness		±1		dB
Gain Variation Over Temperature		0.015		dB/ °C
Noise Figure		4.5		dB
Input Return Loss		15		dB
Output Return Loss		15		dB
Output Power for 1 dB Compression (P1dB)	17	20		dBm
Saturated Output Power (Psat)		22		dBm
Output Third Order Intercept (IP3)		34		dBm
Phase Noise @ 100 Hz, Psat, 10 GHz		-157		dBc/Hz
Phase Noise @ 1 kHz, Psat, 10 GHz		-167		dBc/Hz
Phase Noise @ 10 kHz, Psat, 10 GHz		-176		dBc/Hz
Phase Noise @ 100 kHz, Psat, 10 GHz		-180		dBc/Hz
Supply Current		170	200	mA



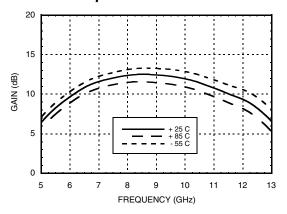


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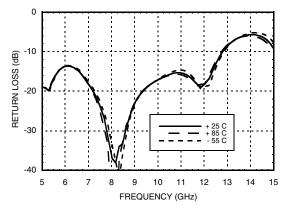
Gain & Return Loss



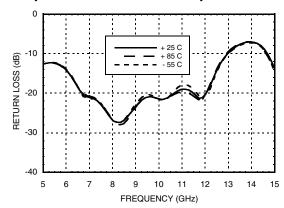
Gain vs. Temperature



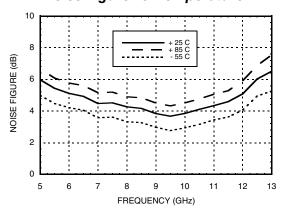
Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature

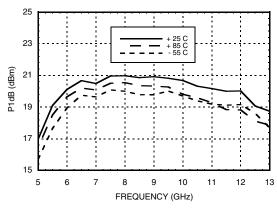




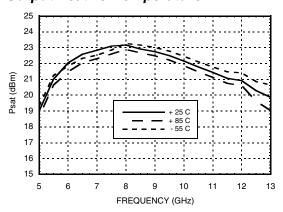


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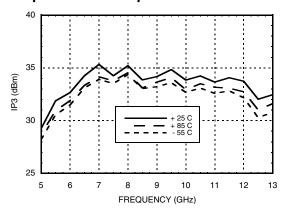
Output P1dB vs. Temperature



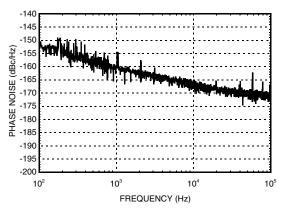
Output Psat vs. Temperature



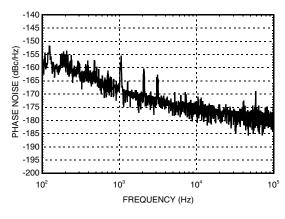
Output IP3 vs. Temperature



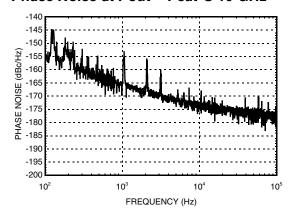
Phase Noise at Pout = 10 dBm @ 10 GHz



Phase Noise at Pout = P1dB @ 10 GHz



Phase Noise at Pout = Psat @ 10 GHz







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Absolute Maximum Ratings

Bias Supply Voltage (Vdc)	+8V	
RF Input Power (RFIN)	+15 dBm	
Continuous Pdiss (T = 85 °C)	1.62W	
Channel Temperature	135 °C	
Thermal Resistance	20 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	



Pin Descriptions

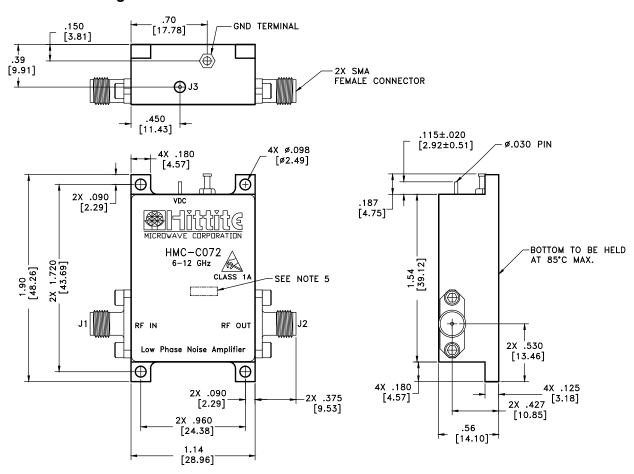
Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO— —
2	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ ├─○ RFOUT
3	Vdc	Power supply voltage for the amplifier. (+7V to +8V)	Vdc O
4	GND	Power supply ground.	GND =





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Outline Drawing



Package Information

Package Type	C-16
Package Weight	107 gms ^[1]

[1] ±1 gms Tolerance

NOTES

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE.
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. TOLERANCES:
 - $4.1 .XX = \pm .02$
 - 4.2 .XXX = ±.010
- 5. MARK LOT NUMBER ON 0.080 X 0.250 LABEL WHERE SHOWN, WITH 0.030" MIN TEXT HEIGHT.



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AMPLIFIERS



ROHS V

Notes:

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